

AMENDMENTS TO THE SPECIFICATION

Paragraph beginning at page 1, line numbered 6:

The present invention relates to a dielectric ceramic, a manufacturing method thereof, and a multilayer ceramic capacitor formed of this dielectric ceramic. In particular, the present invention relates to improvements in the dielectric constant of a dielectric ceramic, in the temperature characteristics of the dielectric constant of a dielectric ceramic layer which is formed of the above dielectric ceramic and which forms a multilayer ceramic capacitor, and in the reliability thereof.

Paragraph beginning at page 3, line 1:

However, by firing in a neutral or a reducing atmosphere, in general, a ceramic composed, for example, of barium titanate is extremely reduced, and as a result, a problem may arise in that the ceramic is semiconductorized becomes semiconductive.

JD 4/9/07 Paragraph beginning at page <sup>8</sup>6, line 2:

First, a method for manufacturing a dielectric ceramic, according to the present invention, comprises a first step of obtaining a reaction product composed of a barium titanate base composite oxide represented by the general formula  $(\text{Ba}_{1-h-l-m}\text{Ca}_h\text{Sr}_i\text{Gd}_m)_k(\text{Ti}_{1-y-j-n}\text{Zr}_y\text{Hf}_j\text{Mg}_n)\text{O}_3$ , in which  $0.995 \leq k \leq 1.015$ ,  $0 \leq h \leq 0.03$ ,  $0 \leq i \leq 0.03$ ,  $0.015 \leq m \leq 0.035$ ,  $0 \leq y < 0.05$ ,  $0 \leq j < 0.05$ ,  $0 \leq (y+j) < 0.05$ , and  $0.015 \leq n \leq 0.035$  ~~hold~~, Ba is being partly replaced with Gd, and Ti is being partly replaced with Mg.